## onsemi

### Quad 2-Input OR Gate 74VHC32

#### **General Description**

The VHC32 is an Advanced High Speed CMOS 2–Input OR Gate fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 4 stages including buffer output, which provide high noise immunity and stable output. An input protection circuit ensures that 0 V to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

#### Features

- High Speed:  $t_{PD} = 3.8 \text{ ns}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low Power Dissipation:  $I_{CC} = 2 \mu A \text{ (max.)}$  at  $T_A = 25^{\circ}C$
- High Noise Immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (min.)
- Power Down Protection is Provided on All Inputs
- Low Noise:  $V_{OLP} = 0.8 V (max.)$
- Pin and Function Compatible with 74HC32
- Pb-Free, Halogen Free/BFR Free and RoHS Compliant

#### Logic Symbol

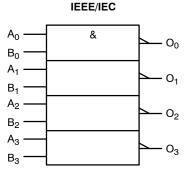
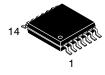


Figure 1. Logic Symbol

TRUTH TABLE

A	В	0
Н	Н	Н
L	Н	Н
Н	L	н
L	L	L



TSSOP-14 WB CASE 948G





XXXXXX= Specific Device Code

- = Assembly Location
- = Wafer Lot

Y = Year

А

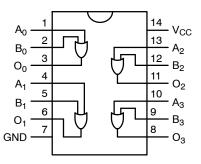
L

W

- = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

#### **CONNECTION DIAGRAM**



#### PIN DESCRIPTION

Pin Names	Description
A <sub>n,</sub> B <sub>n</sub>	Inputs
O <sub>n</sub>	Ouputs

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 4 of this data sheet.

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#### MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +6.5	V
V <sub>IN</sub>	DC Input Voltage	-0.5 to +6.5	V
V <sub>OUT</sub>	DC Output Voltage	–0.5 to V <sub>CC</sub> + 0.5	V
I <sub>IN</sub>	DC Input Current, per Pin	±20	mA
I <sub>OUT</sub>	DC Output Current, Per Pin	±25	mA
Icc	DC Supply Current, V <sub>CC</sub> and GND Pins	±50	mA
I <sub>IK</sub>	Input Clamp Current	-20	mA
I <sub>ОК</sub>	Output Clamp Current	±20	mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 seconds	260	°C
TJ	Junction Temperature Under Bias	+150	°C
$\theta_{JA}$	Thermal Resistance (Note 1)	150	°C/W
PD	Power Dissipation in Still Air at 25°C	833	mW
V <sub>ESD</sub>	ESD Withstand Voltage (Note 2) Human Body Model Charged Device Model	> 2000 N/A	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

 Measured with minimum pad spacing on an FR4 board, using 76mm-by-114mm, 2-ounce copper trace no air flow per JESD51-7.
HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage	2.0	5.5	V
V <sub>IN</sub>	DC Input Voltage (Note 3)	0	5.5	V
V <sub>OUT</sub>	DC Output Voltage (Note 3)	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature	-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise or Fall Rate $V_{CC} = 3.0 \text{ V}$ to 3.6 V $V_{CC} = 4.5 \text{ V}$ to 5.5 V	0 0	100 20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

3. Unused inputs must be held HIGH or LOW. They may not float.

#### DC ELECTRICAL CHARACTERISTICS

						T <sub>A</sub> = 25°C		T <sub>A</sub> = -40°0	C to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Con	ditions	Min	Тур	Max	Min	Max	Unit
VIH	HIGH Level Input	2.0			1.50	-	-	1.50	-	V
	Voltage	3.0–5.5			0.7 x V <sub>CC</sub>	-	-	0.7 x V <sub>CC</sub>	-	
V <sub>IL</sub>	LOW Level Input	2.0			-	-	0.50	-	0.50	V
	Voltage	3.0–5.5			-	-	0.3 x V <sub>CC</sub>	-	0.3 x V <sub>CC</sub>	
V <sub>OH</sub>	HIGH Level Output	2.0	$V_{IN} = V_{IH}$	I <sub>OH</sub> = -50 μA	1.9	2.0	-	1.9	-	V
	Voltage	3.0	or V <sub>IL</sub>		2.9	3.0	-	2.9	-	
		4.5			4.4	4.5	-	4.4	-	
		3.0		I <sub>OH</sub> =4 mA	2.58	-	-	2.48	-	
		4.5		I <sub>OH</sub> =8 mA	3.94	-	-	3.80	-	
V <sub>OL</sub>	LOW Level Output	2.0	$V_{IN} = V_{IH}$	I <sub>OL</sub> = 50 μA	-	0.0	0.1	-	0.1	V
	Voltage	3.0	or V <sub>IL</sub>		-	0.0	0.1	-	0.1	
		4.5			-	0.0	0.1	-	0.1	
		3.0		I <sub>OL</sub> = 4 mA	-	-	0.36	-	0.44	
		4.5		I <sub>OL</sub> = 8 mA	-	-	0.36	-	0.44	
I <sub>IN</sub>	Input Leakage Current	0–5.5	V <sub>IN</sub> = 5.5 V c	or GND	-	-	±0.1	-	±1.0	μΑ
ICC	Quiescent Supply Current	5.5	$V_{IN} = V_{CC}$ or	GND	-	-	2.0	-	20.0	μΑ

#### NOISE CHARACTERISTICS

				T <sub>A</sub> = 25°C		
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Тур	Limits	Unit
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub> (Note 4)	5.0	C <sub>L</sub> = 50 pF	0.3	0.8	V
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub> (Note 4)	5.0	C <sub>L</sub> = 50 pF	-0.3	-0.8	V
V <sub>IHD</sub>	Minimum HIGH Level Dynamic Input Voltage (Note 4)	5.0	C <sub>L</sub> = 50 pF	-	3.5	V
V <sub>ILD</sub>	Maximum LOW Level Dynamic Input Voltage (Note 4)	5.0	C <sub>L</sub> = 50 pF	-	1.5	V

4. Parameter guaranteed by design.

#### AC ELECTRICAL CHARACTERISTICS

				T <sub>A</sub> = 25°C			T <sub>A</sub> = −40°C to +85°C		
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay	3.3 ±0.3	C <sub>L</sub> = 15 pF	-	5.5	7.9	1.0	9.5	ns
			C <sub>L</sub> = 50 pF	-	8.0	11.4	1.0	13.0	
		5.0 ±0.5	C <sub>L</sub> = 15 pF	-	3.8	5.5	1.0	6.5	ns
			C <sub>L</sub> = 50 pF	-	5.3	7.5	1.0	8.5	
C <sub>IN</sub>	Input Capacitance		V <sub>CC</sub> = Open	-	4	10	-	10	pF
C <sub>PD</sub>	Power Dissipation Capacitance		(Note 5)	-	14	-	_	-	pF

5.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC}$  (opr.) =  $C_{PD} \times V_{CC} \times f_{IN} + I_{CC} / 4$  (per gate).

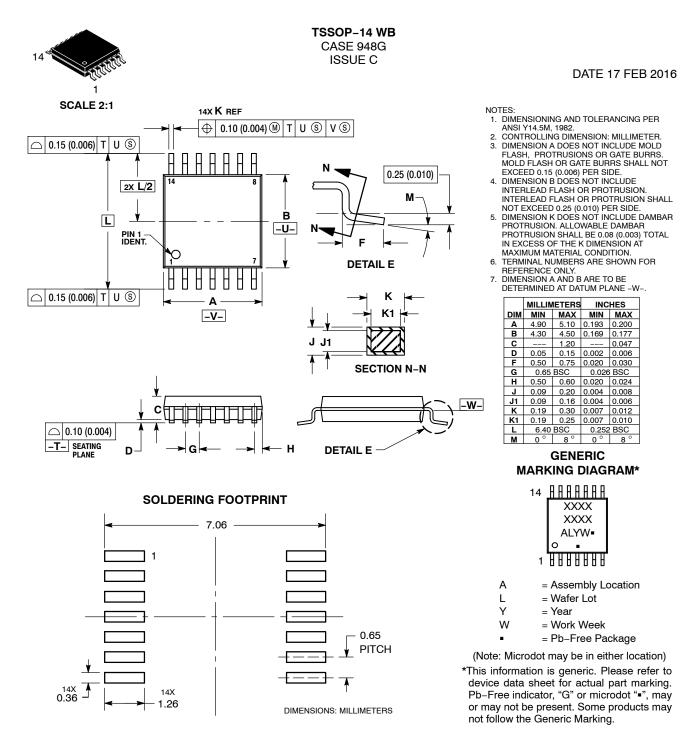
#### **ORDERING INFORMATION**

Device Order Number	Top Marking	Package	Packing Method
74VHC32MTCX	VHC 32	TSSOP-14 WB (Pb-Free, Halide Free)	2,500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

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